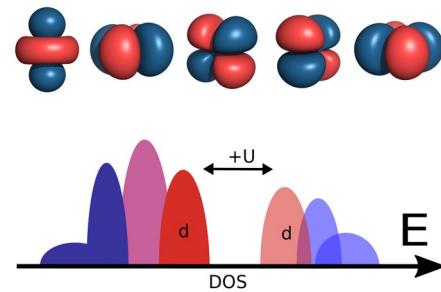

Intricacies of DFT+U, not only in a numeric atom centered orbital framework



Overview

Part I: DFT+U in general

Part II: DFT+U in FHClaims

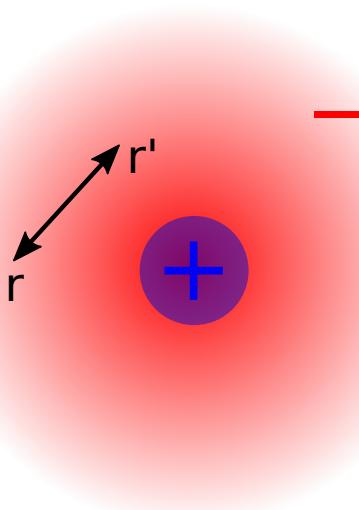


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Page 2

Motivation

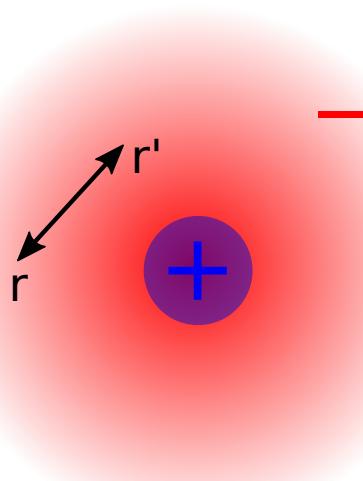
Self-interaction-error (SIE)



$$J [\rho(r)] = \frac{1}{2} \int \int \frac{\rho(r) \rho(r')}{|r - r'|} dr dr'$$

Motivation

Self-interaction-error (SIE)



Solution:

Hybrid-functionals

high-cost

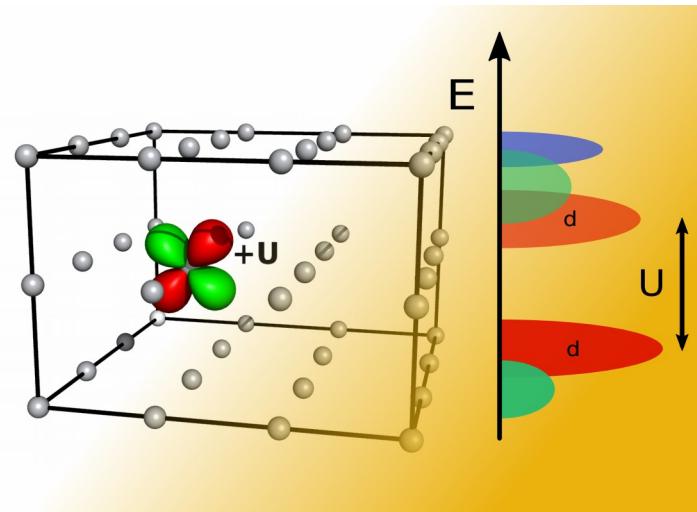
DFT+U

low-cost

d-, f-electrons

Motivation - Theory

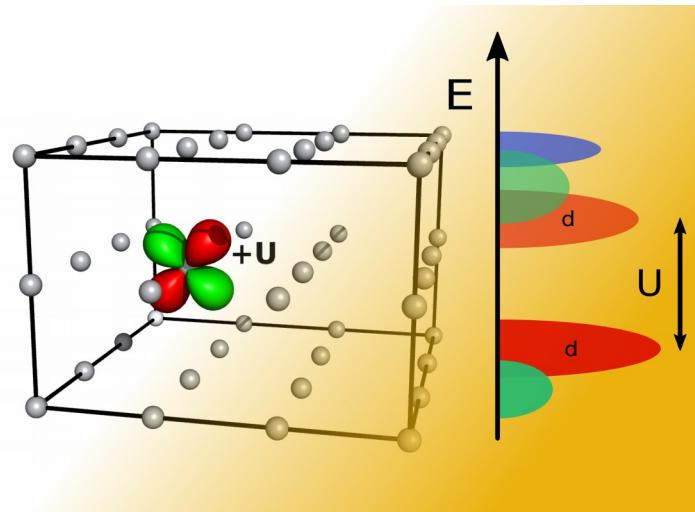
Hubbard-model



$$H_U = U \sum_i c_{i\uparrow}^\dagger c_{i\uparrow} c_{i\downarrow}^\dagger c_{i\downarrow} - t \sum_{\langle ij \rangle, \sigma} (c_{i\sigma}^\dagger c_{j\sigma} - c_{j\sigma}^\dagger c_{i\sigma})$$

Motivation - Theory

General DFT+U Functional



$$E_{\text{DFT+U}} [\rho(\mathbf{r})] = E_{\text{DFT}} [\rho(\mathbf{r})] + E_{\text{U}}^0 [n_{Im}] - E_{\text{dc}} [n_{Im}]$$

Motivation - Theory

Hubbard-Term

$$\begin{aligned} E_U^0 [\{n_{mm'}\}] = \\ \frac{1}{2} \sum_{\sigma} \sum_I \sum_{\{m\}} & \langle m, m'' | \hat{V}_{ee} | m', m'' \rangle n_{Imm'}^{\sigma} n_{Im''m''}^{-\sigma} \\ + (\langle m, m''' | \hat{V}_{ee} | m', m''' \rangle & \\ - \langle m, m'' | \hat{V}_{ee} | m''', m' \rangle) n_{Imm'}^{\sigma} n_{Im''m''}^{\sigma} \end{aligned}$$

Motivation - Theory

Spherically averaged form of DFT+U

$$E_U [\{n_{Imm'}^\sigma\}] = \frac{1}{2} \sum_{\sigma, I} U_{\text{eff}}^I [Tr (\mathbf{n}_I^\sigma) - Tr (\mathbf{n}_I^\sigma \mathbf{n}_I^\sigma)]$$

Main quantity: DFT+U occupation matrix \mathbf{n}_I^σ



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Motivation - Theory

Spherically averaged form of DFT+U

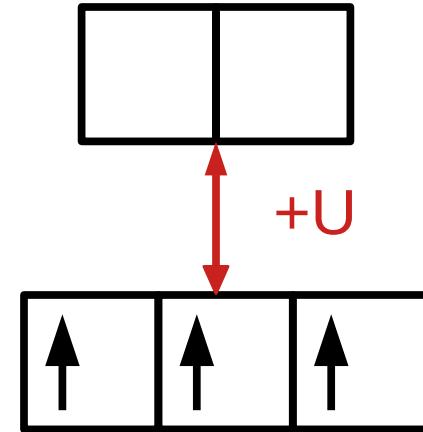
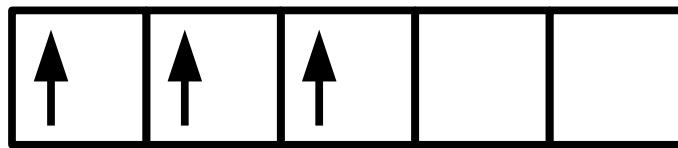
$$E_U [\{n_{Imm'}^\sigma\}] = \frac{1}{2} \sum_{\sigma, I} U_{\text{eff}}^I [Tr (\mathbf{n}_I^\sigma) - Tr (\mathbf{n}_I^\sigma \mathbf{n}_I^\sigma)]$$

Main quantity: DFT+U occupation matrix \mathbf{n}_I^σ

\mathbf{n}_I^σ : how many electrons at a certain lattice site

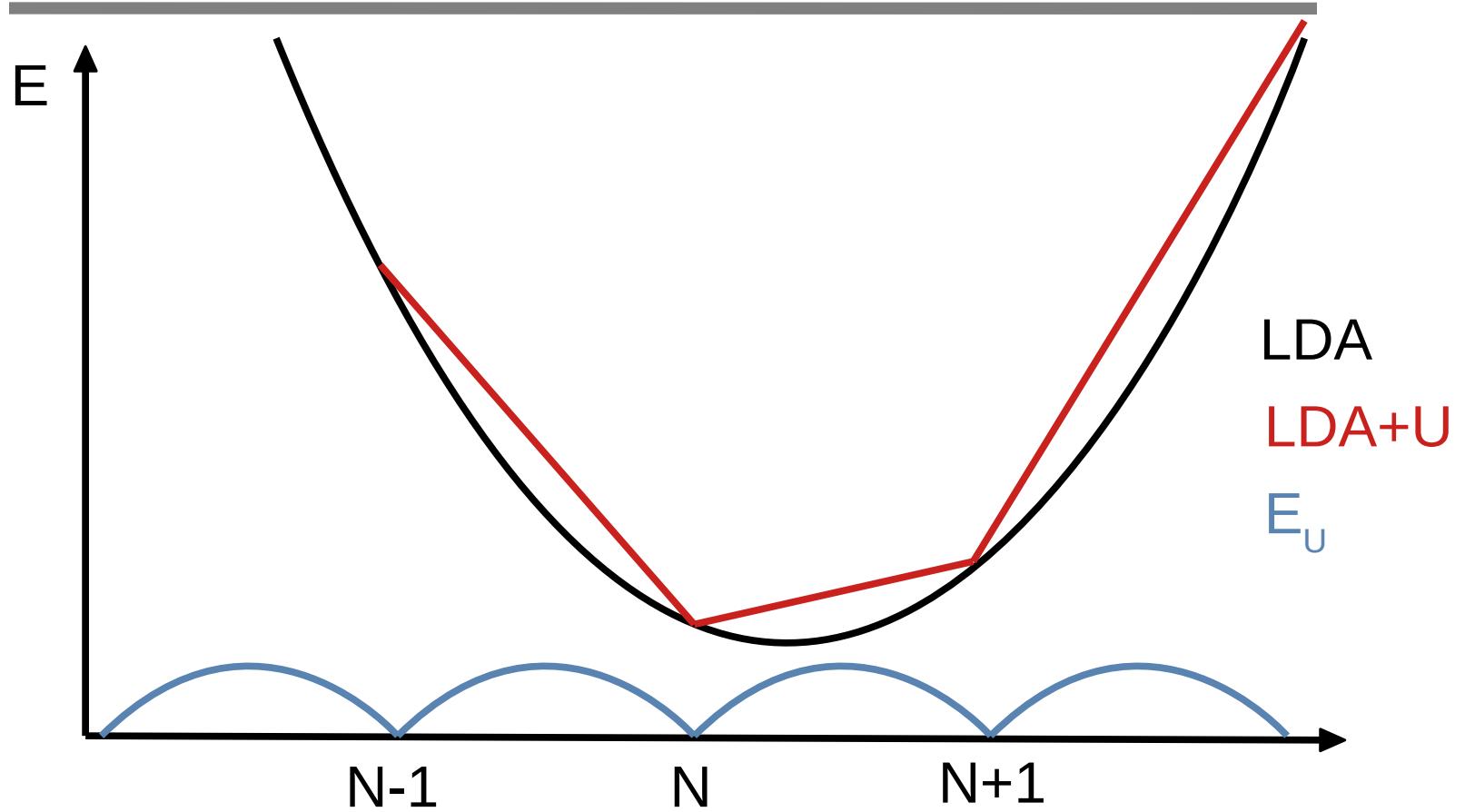


How does it work?



$$v_{mm'} = -U \left(n_{mm'} - \frac{1}{2} \right)$$

How does it work?

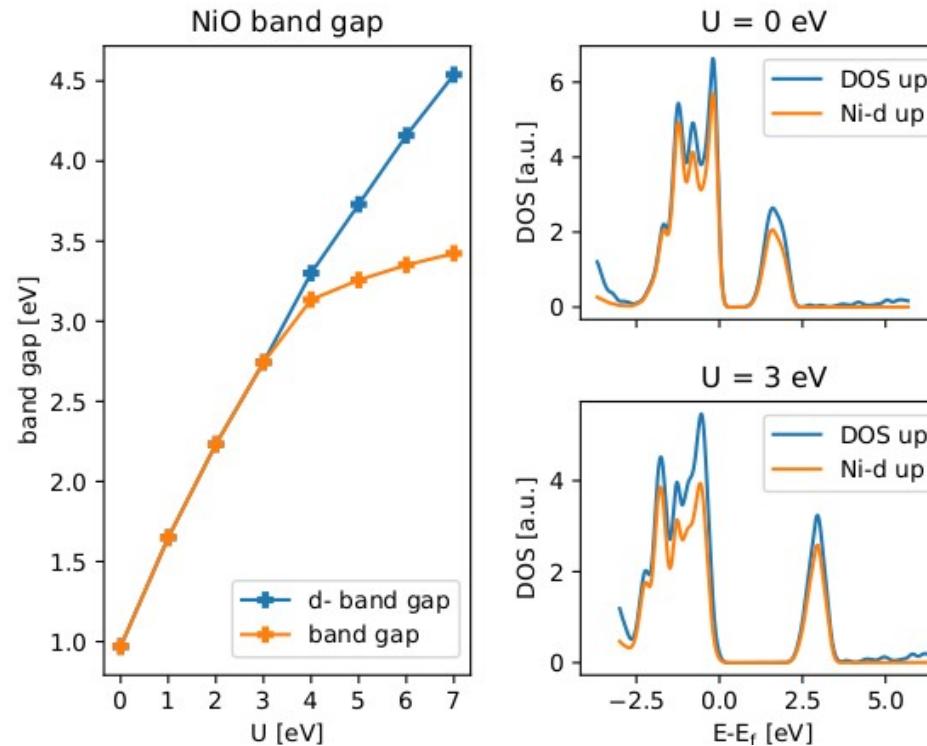


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Page 11

How does it work?

NiO



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Page 12

DFT+U Occupation Matrix

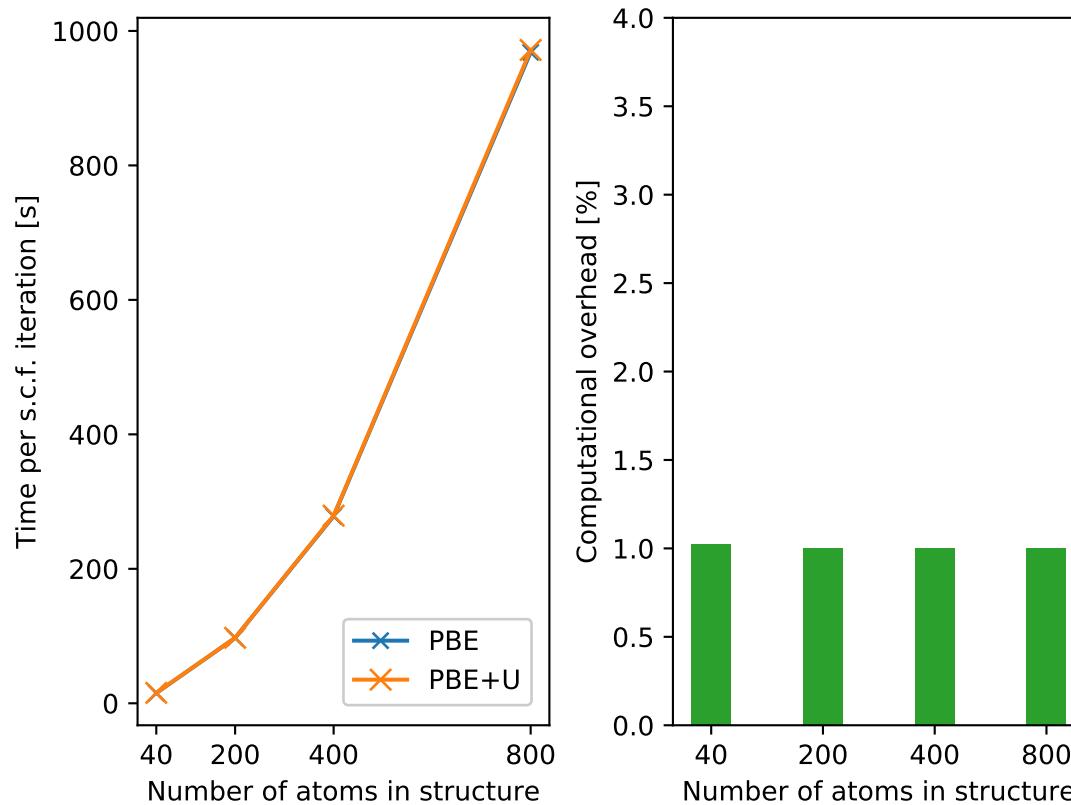
Problem: How to identify localized states from the KS-spectrum

$$n_{Imm'}^\sigma = \sum_\gamma f_\gamma \langle \Psi_\gamma^\sigma | \hat{P}_{Imm'}^\sigma | \Psi_\gamma^\sigma \rangle$$

Computational cost is negligible, evaluation of \mathbf{n}_I^σ is reduced to finding the correct entries of the density matrix



DFT+U Occupation Matrix



DFT+U Occupation Matrix

Problem: How to identify localized states from the KS-spectrum

$$n_{Imm'}^\sigma = \sum_\gamma f_\gamma \langle \Psi_\gamma^\sigma | \hat{P}_{Imm'}^\sigma | \Psi_\gamma^\sigma \rangle$$

on-site

$$\hat{P}_{Imm'}^\sigma = |\tilde{\phi}_{Im'}^\sigma\rangle\langle\tilde{\phi}_{Im}^\sigma|$$

$$|\tilde{\phi}_{Im}^\sigma\rangle = \sum_q c_{Imq}^\sigma |\tilde{\psi}_{Imq}^\sigma\rangle$$



Part II: DFT+U in FHClaims

(or DFT+U in electronic structure codes with localized basis functions)



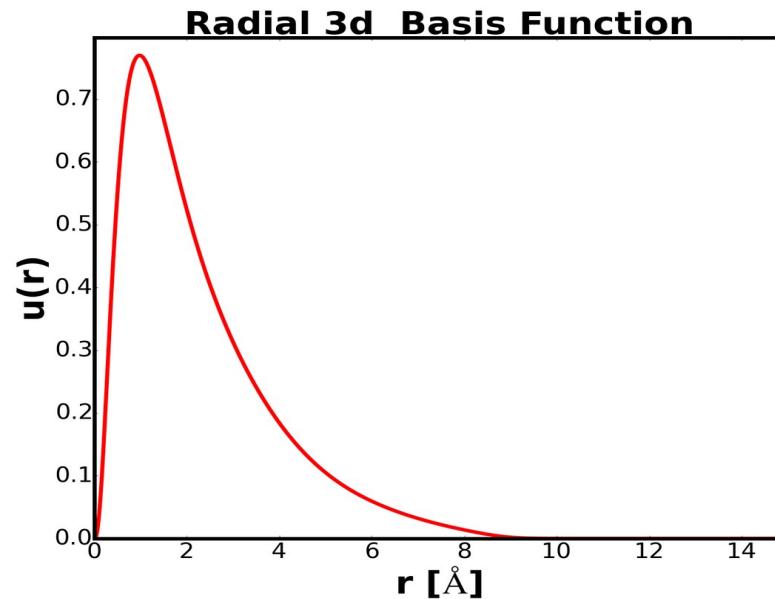
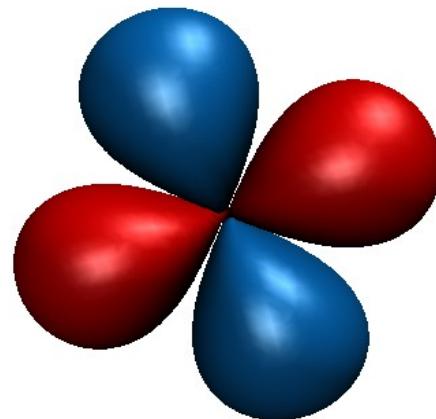
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Page 16

Hubbard Projectors

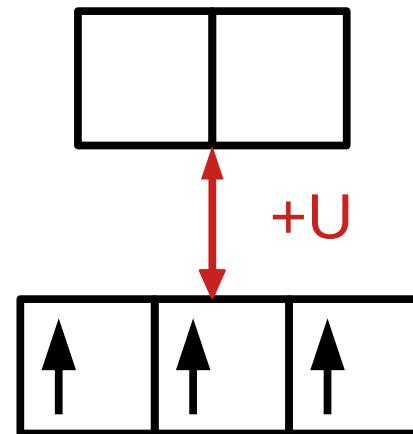
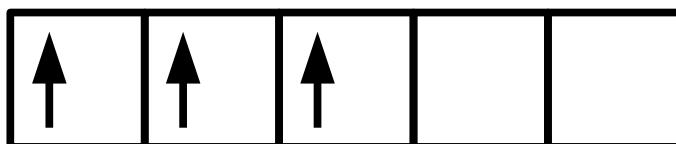
$$\psi_i(r) = \frac{u_i(r)}{r} Y_{lm}(\Omega)$$

“minimal basis set is default”



Hubbard Projectors

Not “fully true” anymore



penalize basis functions

better to speak of a correlated subspace

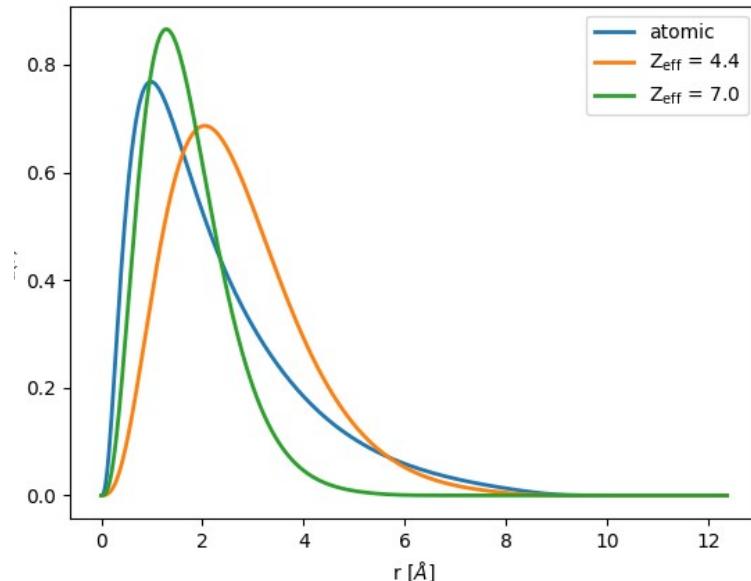
$$v_{mm'} = -U \left(n_{mm'} - \frac{1}{2} \right)$$

Hubbard Projectors

Titanium basis set

```
# "First tier"
    hydro 4 f 8
    hydro 3 d 2.7
    ionic 4 p auto
    hydro 5 g 11.6
    ionic 4 s auto
# "Second tier"
    hydro 3 d 4.4
```

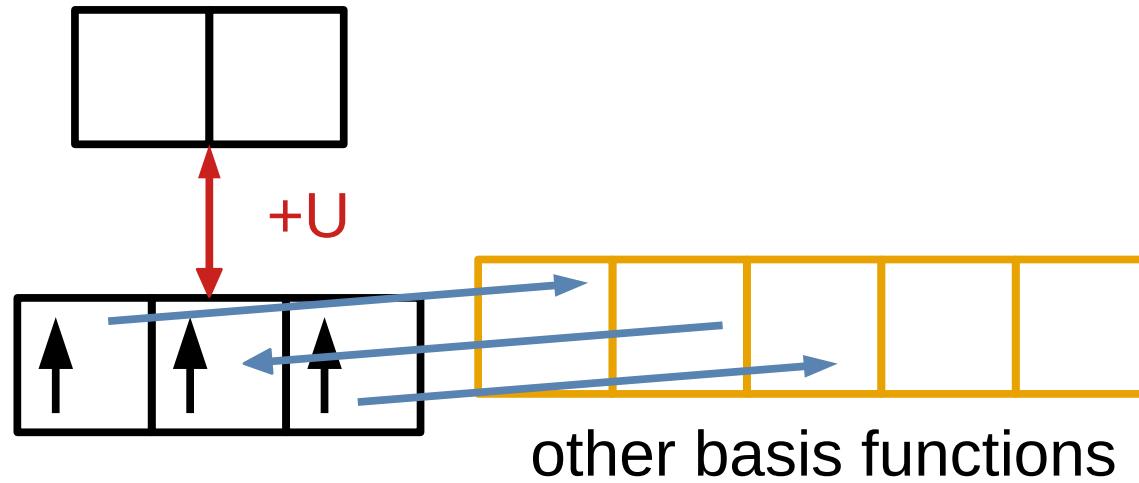
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Page 19

My electrons disappear



Energy penalty depending on the occupation numbers

My electrons disappear

What can I do?

adjust U value

initial structure is bad

use DFT+U occupation matrix control

Include other basis functions also in DFT+U description



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Page 21

Matrix Control

Fix \mathbf{n}_I^σ for entire run will fix DFT+U potential and increases stability

$$v_{mm'} = -U_{\text{eff}} \left(n_{mm'} - \frac{1}{2} \right)$$

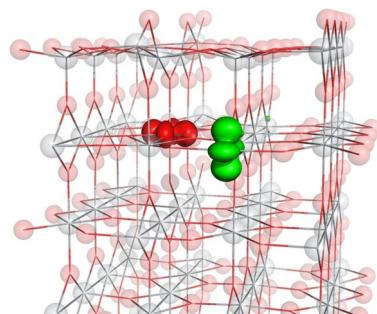
Occupation numbers from a PBE run, HSE06 run or completely user defined

Use the obtained restart information to make it self-consistently



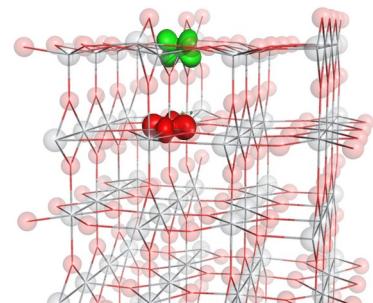
Matrix Control: Examples

localize excess electrons in TiO_2



a) Ti 3d

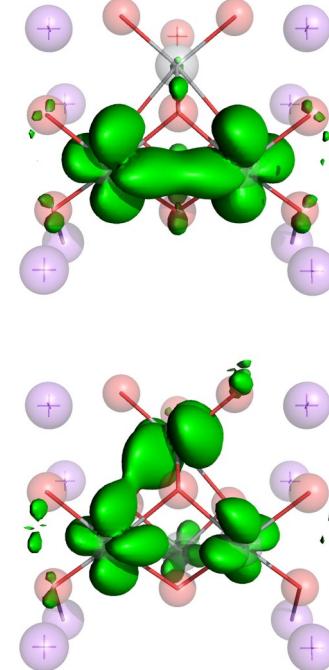
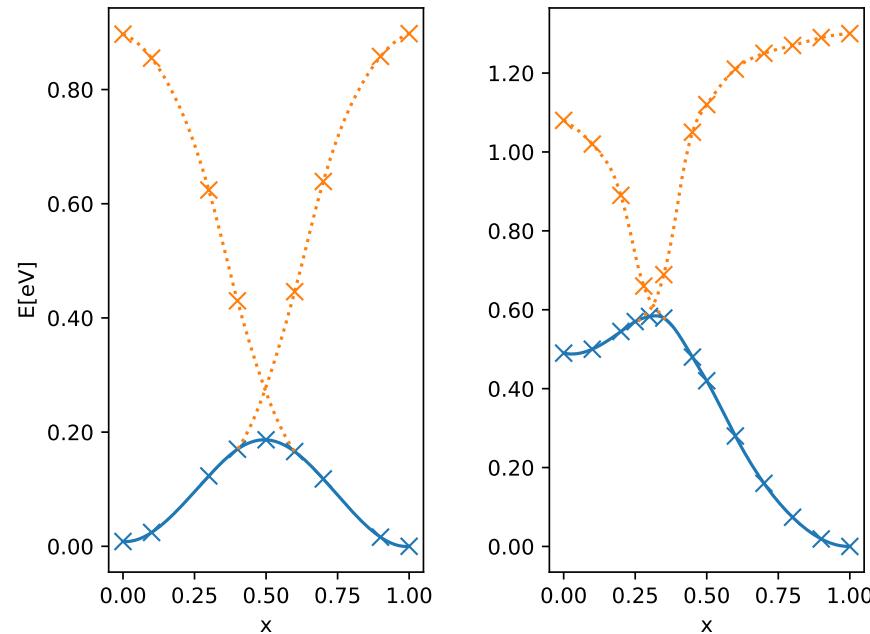
0.12	0.00	0.04	0.00	0.00
0.00	0.13	0.00	0.04	0.00
0.04	0.00	0.09	0.00	0.00
0.00	0.04	0.00	0.13	0.00
0.00	0.00	0.00	0.00	0.09



b) Ti 3d modified

0.12	0.00	0.04	0.00	0.00
0.00	0.13	0.00	0.04	0.00
0.04	0.00	1.00	0.00	0.00
0.00	0.04	0.00	0.13	0.00
0.00	0.00	0.00	0.00	0.09

Matrix Control: Examples



calculation of polaron hopping
barriers and transition states



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Page 24

Conclusion

DFT+U corrects SIE (similar to hybrid functionals)

Ambiguities come mainly from the projector functions

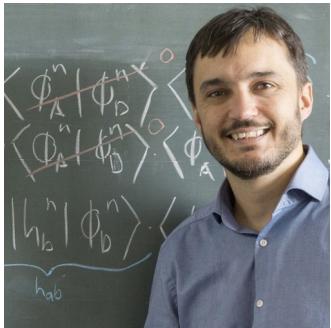
Negligible computational cost compared to LDA/GGA

Occupation matrix control extremely powerful
Enables the treatment of systems which otherwise are pathologically



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Thank you for your attention!



DFG Deutsche
Forschungsgemeinschaft

Implementation

